

4-Bit Bidirectional Voltage-Level Translator for Open-Drain and Push-Pull Application

UM3284FUE TSSOP14
UM3284FQA QFN12 1.7×2.0
UM3284FQS QFN14 3.5×3.5
UM3284FQV QFN12 1.8×1.8

1 Description

The UM3284F is 4-channel ESD-protected level translator provides the level shifting necessary to allow data transfer in a multi-voltage system. Externally applied voltages, V_{CCB} and V_{CCA} , set the logic levels on either side of the device. A low-voltage logic signal present on the V_{CCA} side of the device appears as a high-voltage logic signal on the V_{CCB} side of the device, and vice-versa. The UM3284F bidirectional level translator utilizes a transmission-gate based design to allow data translation in either direction ($V_{CCA} \leftrightarrow V_{CCB}$) on any single data line. When $V_{CCA} \leq V_{CCB}$, the recommended voltage range for V_{CCA} and V_{CCB} is from 1.1V to 5.5V, when $V_{CCA} > V_{CCB}$, the recommended voltage range for V_{CCA} and V_{CCB} is from 1.4V to 5.5V.

This device is fully specified for partial-power-down applications using I_{OFF} . The I_{OFF} circuitry disables the outputs, thus preventing damaging current backflow through the device when it is powered down. The V_{CC} isolation feature is designed so that if either V_{CC} input supply is below 100mV, all level shifter outputs are disabled and placed into a high impedance state. The UM3284F enters a three-state output mode to reduce supply current when output enable (OE) is low. The UM3284F is designed so that the OE input circuit is supplied by V_{CCA} . $\pm 8kV$ ESD protection on both sides for greater protection in applications that route signals externally.

The UM3284F series are available in TSSOP14, QFN12 1.7×2.0, QFN12 1.8×1.8 and QFN14 3.5×3.5 packages.

2 Applications

- SPI, MICROWIRE, and I²C Level Translation
- Handsets
- Smart phones
- Tablets
- Desktop PCs

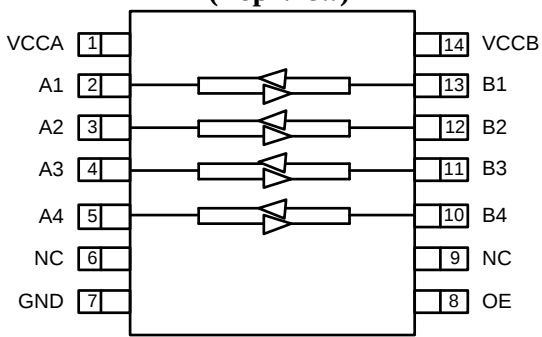
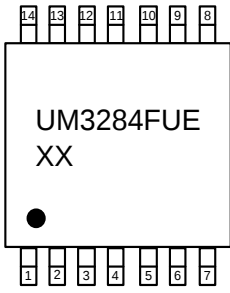
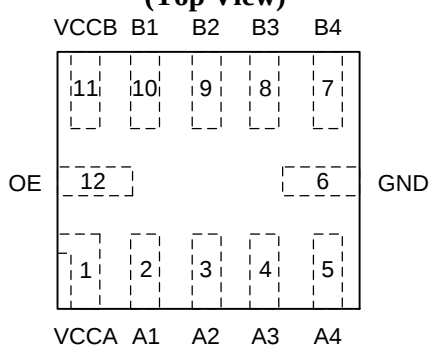
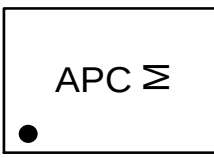
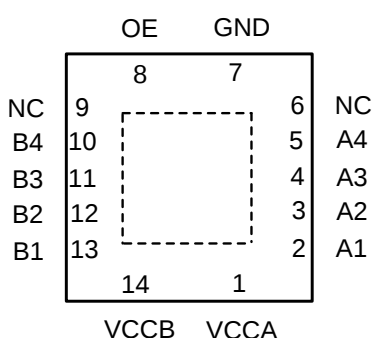
3 Features

- Max Data Rates
 - 100Mbps (Push-pull, 1.8V to 3.3V)
 - 2Mbps (Open-drain)
- V_{CCA} and V_{CCB} are independent: V_{CCA} may be greater than, equal to, or less than V_{CCB}
- I_{OFF} supports partial power-down mode operation
- V_{CC} isolation feature – if either V_{CC} input is at GND, all are in the high-impedance state
- No Direction-Control Signal Needed
- No Power-Supply Sequencing Required
 V_{CCA} or V_{CCB} Can Be Ramped First
- Low Power Consumption
- ESD protection on A and B port:
 - $\pm 8kV$ Human-Body Model
- Latch-Up Performance Exceeds 200mA

4 Ordering Information

Part Number	Mark Code	Package Type	Shipping Qty
UM3284FUE	UM3284FUE	TSSOP14	3000pcs/13Inch Tape & Reel
UM3284FQA	APC	QFN12 1.7×2.0	3000pcs/7Inch Tape & Reel
UM3284FQS	UM3284FQS	QFN14 3.5×3.5	3000pcs/13Inch Tape & Reel
UM3284FQV	GA	QFN12 1.8×1.8	3000pcs/7Inch Tape & Reel

5 Pin Configuration and Function

(Top View) 	 XX: Week Code UM3284FUE TSSOP14
(Top View) 	 M: Month Code UM3284FQA QFN12 1.7×2.0
(Top View) 	 XX: Week Code UM3284FQS QFN14 3.5×3.5

5 Pin Configuration and Function (continued)

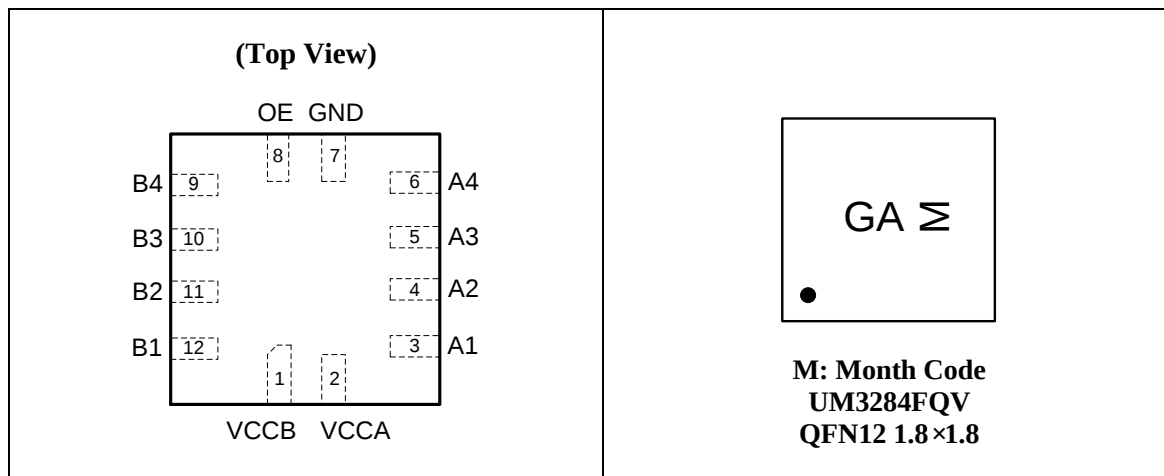


Table 5-1. Pin Functions

Pin Name	Function
VCCA	A-Port supply voltage $1.1V \leq V_{CCA} \leq 5.5V$.
A1	Input/output 1. Referenced to V_{CCA} .
A2	Input/output 2. Referenced to V_{CCA} .
A3	Input/output 3. Referenced to V_{CCA} .
A4	Input/output 4. Referenced to V_{CCA} .
GND	Ground.
OE	3-state output enable input. Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA} .
NC	Not connected.
B4	Input/output 4. Referenced to V_{CCB} .
B3	Input/output 3. Referenced to V_{CCB} .
B2	Input/output 2. Referenced to V_{CCB} .
B1	Input/output 1. Referenced to V_{CCB} .
VCCB	B-Port supply voltage. $1.1V \leq V_{CCB} \leq 5.5V$

6 Specifications

6.1 Absolute Maximum Ratings (Note 1)

Over operating free-air temperature range (unless otherwise noted)

Symbol	Parameter		Value	Unit
V_{CCA}	Supply Voltage Range		-0.5 to +6.5	V
V_{CCB}	Supply Voltage Range		-0.5 to +6.5	V
V_I	Input Voltage Range	A ports	-0.5 to +6.5	V
		B ports	-0.5 to +6.5	
V_O	Voltage Range applied to any output in the high-impedance or power-off state	A ports	-0.5 to +6.5	V
		B ports	-0.5 to +6.5	
V_O	Voltage Range applied to any output in the high or low state (Note 2)	A ports	-0.5 to ($V_{CCA}+0.5$)	V
		B ports	-0.5 to ($V_{CCB}+0.5$)	
V_{ESD}	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001	All pins	± 8	kV
I_{IK}	Input Clamp Current	$V_I < 0$	-50	mA
I_{OK}	Output Clamp Current	$V_O < 0$	-50	mA
I_O	Continuous Output Current		± 50	mA
	Continuous Current through V_{CCA} , V_{CCB} , or GND		± 100	mA
T_{OP}	Operating Temperature Range		-40 to +125	°C
T_J	Junction Temperature Range		-40 to +150	°C
T_{STG}	Storage Temperature Range		-65 to +150	°C

Note 1: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Note 2: Maximum voltage must not exceed 6.5V.

6.2 Recommended Operating Conditions (Note 1, 2)

Symbol	Parameter		V _{CCA}	V _{CCB}	Min	Max	Unit
V _{CCA}	Supply Voltage		V _{CCA} ≤ V _{CCB}		1.1	5.5	V
V _{CCB}					1.1	5.5	
V _{CCA}	Supply Voltage		V _{CCA} > V _{CCB}		1.4	5.5	
V _{CCB}					1.4	5.5	
V _{IH}	High Level Input Voltage	A- Port	1.1V to 1.95V	1.1V to 5.5V	V _{CCI} -0.2	V _{CCI}	
			1.95V to 5.5V		V _{CCI} -0.4	V _{CCI}	
		B- Port	1.1V to 5.5V	1.1V to 1.95V	V _{CCI} -0.2	V _{CCI}	
					V _{CCI} -0.4	V _{CCI}	
		OE	1.1V to 5.5V	1.1V to 5.5V	V _{CCA} ×0.65	5.5	
V _{IL}	Low Level Input Voltage	A- Port	1.1V to 5.5V	1.1V to 5.5V	0	0.15	ns/V
		B- Port			0	0.15	
		OE			0	V _{CCA} ×0.35	
Δt/Δv	Input Transition Rise or Fall Time	A-Port push-pull driving	1.1V to 5.5V	1.1V to 5.5V		10	
		B-Port push-pull driving				10	
		Control input				10	

Note1. V_{CCI} is the supply voltage associated with the input port.

Note2. V_{CCO} is the supply voltage associated with the output port.

6.3 Thermal Information

Symbol	Parameter		Value	Unit
R _{θJA}	Junction-to-ambient thermal resistance	TSSOP14	120.5	℃/W
		QFN12 1.7×2.0	119.8	
		QFN14 3.5×3.5	55.4	
R _{θJC(TOP)}	Junction-to-case (top) thermal resistance	TSSOP14	49.7	℃/W
		QFN12 1.7×2.0	42.6	
		QFN14 3.5×3.5	68.3	
R _{θJB}	Junction-to-board thermal resistance	TSSOP14	62.3	℃/W
		QFN12 1.7×2.0	52.5	
		QFN14 3.5×3.5	31.6	

6.4 Electrical Characteristics

Over recommended operating free-air temperature range (unless otherwise noted)

Parameter		Test Conditions	V _{CCA}	V _{CCB}	Min	Typ	Max	Unit
V _{OHA}		I _{OH} =-20μA V _{IB} ≥V _{CCB} -0.2V	1.1V to 5.5V	1.1V to 5.5V	V _{CCA} × 0.67	V _{CCA} -0.1		V
V _{OLA}		I _{OL} =20uA, V _{IB} ≤0.15V	1.1V to 5.5V	1.1V to 5.5V			0.4	V
		I _{OL} =180uA, V _{IB} ≤0.15V	1.4V	1.4V to 5.5V			0.4	
		I _{OL} =220uA, V _{IB} ≤0.15V	1.65V	1.4V to 5.5V			0.4	
		I _{OL} =300uA, V _{IB} ≤0.15V	2.3V	1.4V to 5.5V			0.4	
		I _{OL} =400uA, V _{IB} ≤0.15V	3V	1.4V to 5.5V			0.55	
		I _{OL} =620uA, V _{IB} ≤0.15V	4.5V	1.4V to 5.5V			0.55	
V _{OHB}		I _{OH} =-20μA V _{IA} ≥V _{CCA} -0.2V	1.1V to 5.5V	1.1V to 5.5V	V _{CCB} × 0.67	V _{CCB} -0.1		V
V _{OLB}		I _{OL} =20uA, V _{IA} ≤0.15V	1.1V to 5.5V	1.1V to 5.5V			0.4	V
		I _{OL} =180uA, V _{IA} ≤0.15V	1.4V to 5.5V	1.4V			0.4	
		I _{OL} =220uA, V _{IA} ≤0.15V	1.4V to 5.5V	1.65V			0.4	
		I _{OL} =300uA, V _{IA} ≤0.15V	1.4V to 5.5V	2.3V			0.4	
		I _{OL} =400uA, V _{IA} ≤0.15V	1.4V to 5.5V	3V			0.55	
		I _{OL} =620uA, V _{IA} ≤0.15V	1.4V to 5.5V	4.5V			0.55	
I _I	OE	V _I =V _{CCI} or GND	1.1V to 5.5V	1.1V to 5.5V	-2		2	μA
I _{OZ}	A or B Port	OE=V _{IL} V _I =V _{CCI} or GND	1.1V to 5.5V	1.1V to 5.5V	-2		2	μA
I _{OFF}	A or B Port	V _I or V _O = 0 to 5.5V	0V	0V to 5.5V	-5	0.1	5	μA
			0V to 5.5V	0V	-5	0.1	5	
I _{CCA}		V _I =V _O =open, I _O =0	1.1V to 5.5V	1.1V to 5.5V		2	6	μA
			5.5V	0V			3	
			0V	5.5V			1	
I _{CCB}		V _I =V _O =open, I _O =0	1.1V to 5.5V	1.1V to 5.5V			12	μA
			5.5V	0V			1	
			0V	5.5V			3	
I _{CCA} +I _{CCB}		V _I =V _O =open, I _O =0	1.1V to 5.5V	1.1V to 5.5V			18	μA
I _{CCZA}		V _I =V _O =open, I _O =0, OE=GND	1.1V to 5.5V	1.1V to 5.5V			2	μA
I _{CCZB}		V _I =V _O =open, I _O =0, OE=GND	1.1V to 5.5V	1.1V to 5.5V			5	μA
C _I	OE		3.3V	3.3V			5.5	pF
C _{IO}	A Port		3.3V	3.3V			7	pF
	B Port						6	

Note 1. When V_{CCA} > V_{CCB}, the recommended voltage range for V_{CCA} and V_{CCB} is from 1.4V to 5.5V.

6.5 Switching Characteristics (Note 1, 2)

Over recommended operating free-air temperature range, $V_{CCA} = 1.2 \pm 0.1V$ (unless otherwise noted).

Parameter	Test Conditions		V _{CCB} (V)										Unit	
			1.2±0.1	1.5±0.1		1.8±0.15		2.5±0.2		3.3±0.3		5±0.5		
			Typ	Min Max		Min Max		Min Max		Min Max		Min Max		
t _{PHL}	A-B	P-P	28	30		30		40		50		70		ns
		O-D	23	4	25	4	25	3.6	30	3.5	40	3.5	45	
t _{PLH}	A-B	P-P	32	25		25		25		30		35		
		O-D	950	190	820	182	720	143	554	114	473	81	384	
t _{PHL}	B-A	P-P	28	25		25		25		20		25		ns
		O-D	23	4	26	3.4	25	3.1	25	2.8	20	2.5	20	
t _{PLH}	B-A	P-P	32	35		30		30		25		25		
		O-D	950	190	850	186	745	147	603	118	519	84	407	
t _{EN}	OE-A	P-P	0.25	0.2		0.2		0.2		0.2		0.2		us
	OE-B	P-P	0.25	0.2		0.2		0.2		0.2		0.2		us
t _{DIS}	OE-A OE-B	P-P	0.2	0.4		0.4		0.4		0.4		0.4		us
t _{RA}	A port rise time	P-P	37	3	50	3.5	45	3	40	3.1	40	3.2	40	ns
		O-D	702	135	1050	147	982	115	716	92	592	66	481	
t _{RB}	B port rise time	P-P	37	3	30	2.9	25	1.9	20	0.9	16.1	0.7	2.6	ns
		O-D	712	135	1050	135	1020	91	756	58	653	20	600	
t _{FA}	A port fall time	P-P	37	3	40	2.3	35	1.7	30	1.6	30	1.7	30	ns
		O-D	21.5	3	40	2.4	35	2.1	30	1.7	30	1.5	30	
t _{FB}	B port fall time	P-P	36	3	40	2	35	1.3	35	0.9	40	0.8	55	ns
		O-D	22	3	30	1.2	25	1.3	25	1	26	0.5	32	
t _{SK(O)}	Channel-to-Channel	P-P	1	1		1		1		1.1		1		ns
Max data rate	A to B	P-P	8	30		30		15		12		5		Mbps
		O-D	0.8	0.8		0.8		0.8		0.8		0.8		
Max data rate	B to A	P-P	8	10		10		10		10		8		Mbps
		O-D	0.8	0.8		0.8		0.8		0.8		0.8		

Note 1: P-P means push-pull; O-D means Open-drain.

Note 2: The duty cycle of the output signal ranges from 40% to 60%.

6.5 Switching Characteristics (Note 1, 2) (continued)

Over recommended operating free-air temperature range, $V_{CCA} = 1.5V \pm 0.1V$ (unless otherwise noted).

Parameter	Test Conditions		V_{CCB} (V)					Unit
			1.5 $\pm$ 0.1	1.8 $\pm$ 0.15	2.5 $\pm$ 0.2	3.3 $\pm$ 0.3	5 $\pm$ 0.5	
			Min Max	Min Max	Min Max	Min Max	Min Max	
t_{PHL}	A-B	P-P	20	15	13	12	12	ns
		O-D	4 20	4 15.5	3.6 12.8	3.5 12.2	3.5 12	
t_{PLH}	A-B	P-P	15	12	10	9.8	9.7	ns
		O-D	190 820	182 720	143 554	114 473	81 384	
t_{PHL}	B-A	P-P	20	15	13	12	12	ns
		O-D	4 20	3.4 15.5	3.1 14	2.8 15	2.5 14	
t_{PLH}	B-A	P-P	15	12	10	9.8	9	ns
		O-D	190 850	186 745	147 603	118 519	84 407	
t_{EN}	OE-A	P-P	5	0.2	0.2	0.2	0.2	us
	OE-B	P-P	0.2	0.2	0.2	0.2	0.2	us
t_{DIS}	OE-A OE-B	P-P	0.4	0.4	0.4	0.4	0.4	us
t_{RA}	A port rise time	P-P	3 15	3.5 14.5	3 13	3.1 13	3.2 13	ns
		O-D	135 1050	147 982	115 716	92 592	66 481	
t_{RB}	B port rise time	P-P	3 15	2.9 11.4	1.9 7.4	0.9 4.7	0.7 2.6	ns
		O-D	135 1050	135 1020	91 756	58 653	20 370	
t_{FA}	A port fall time	P-P	3 15	2.3 13	1.7 10	1.6 10	1.7 9	ns
		O-D	3 15	2.4 12	2.1 11	1.7 11	1.5 10	
t_{FB}	B port fall time	P-P	3 15	2 13	1.3 8.5	0.9 8.5	0.8 5.1	ns
		O-D	3 15	1.2 11.5	1.3 8.6	1 9.6	0.5 7.7	
$t_{SK(O)}$	Chan- el-to-Ch annel	P-P	1	1	1	1.1	1	ns
Max data rate	A to B	P-P	50	70	100	100	90	Mbps
		O-D	2	2	2	2	2	
Max data rate	B to A	P-P	50	50	50	50	50	Mbps
		O-D	2	2	2	2	2	

Note 1: P-P means push-pull; O-D means Open-drain.

Note 2: The duty cycle of the output signal ranges from 40% to 60%.

6.5 Switching Characteristics (Note 1, 2) (continued)

Over recommended operating free-air temperature range, $V_{CCA} = 1.8V \pm 0.15V$ (unless otherwise noted).

Parameter	Test Conditions		V_{CCB} (V)					Unit
			1.5 $\pm$ 0.1	1.8 $\pm$ 0.15	2.5 $\pm$ 0.2	3.3 $\pm$ 0.3	5 $\pm$ 0.5	
			Min Max	Min Max	Min Max	Min Max	Min Max	
t_{PHL}	A-B	P-P	20	13	10	10	8	ns
		O-D	4 20	3.6 13.5	3.2 11	3.1 11.1	3.1 10	
t_{PLH}	A-B	P-P	15	9	10	6.5	6.3	ns
		O-D	190 820	194 729	155 584	126 466	90 346	
t_{PHL}	B-A	P-P	20	13	10	10	9	ns
		O-D	4 20	3.4 13.5	2.8 12	2.5 12.5	2.1 11	
t_{PLH}	B-A	P-P	15	10.2	10	10	7	ns
		O-D	190 850	197 733	159 578	129 459	93 323	
t_{EN}	OE-A	P-P	30	5	0.2	0.2	0.2	us
	OE-B	P-P	0.2	0.2	0.2	0.2	0.2	us
t_{DIS}	OE-A OE-B	P-P	0.4	0.4	0.4	0.4	0.4	us
t_{RA}	A port rise time	P-P	3 15	3.1 11.9	2.6 10	2.7 10	2.8 9	ns
		O-D	135 1050	155 996	124 691	100 508	72 350	
t_{RB}	B port rise time	P-P	3 15	2.8 10.5	1.8 7.2	1.2 5.2	0.7 2.7	ns
		O-D	135 1050	132 1001	106 677	73 546	32 323	
t_{FA}	A port fall time	P-P	3 15	2.1 12	1.6 10	1.4 7.5	1.4 7	ns
		O-D	3 15	2.2 10	1.7 10	1.4 8.8	1.2 7.5	
t_{FB}	B port fall time	P-P	3 15	2 12	1.3 10	0.9 3.9	0.7 3	ns
		O-D	3 15	0.8 10.5	0.7 10.7	1 9.6	0.6 5.1	
$t_{SK(O)}$	Chan- el-to-Ch annel	P-P	1	1	1	1	1	ns
Max data rate	A to B	P-P	50	70	100	100	100	Mbps
		O-D	2	2	2	2	2	
Max data rate	B to A	P-P	70	70	75	75	75	Mbps
		O-D	2	2	2	2	2	

Note 1: P-P means push-pull; O-D means Open-drain.

Note 2: The duty cycle of the output signal ranges from 40% to 60%.

6.5 Switching Characteristics (Note 1, 2) (continued)

Over recommended operating free-air temperature range, $V_{CCA} = 2.5V \pm 0.2V$ (unless otherwise noted).

Parameter	Test Conditions		V_{CCB} (V)					Unit
			1.5 $\pm$ 0.1	1.8 $\pm$ 0.15	2.5 $\pm$ 0.2	3.3 $\pm$ 0.3	5 $\pm$ 0.5	
			Min Max	Min Max	Min Max	Min Max	Min Max	
t_{PHL}	A-B	P-P	20	13	8	7	6.5	ns
		O-D	4 20	3.6 13.5	2.4 10	2.3 8.8	2.2 8.2	
t_{PLH}	A-B	P-P	15	9	6	5	4.5	ns
		O-D	190 820	194 729	149 592	125 488	93 368	
t_{PHL}	B-A	P-P	20	13	9.4	7.5	7.0	ns
		O-D	4 20	3.4 13.5	2.5 10	2.2 9	1.8 8.5	
t_{PLH}	B-A	P-P	15	10.2	5.9	5.6	4.8	ns
		O-D	190 850	197 733	150 595	126 481	94 345	
t_{EN}	OE-A	P-P	50	30	5	0.2	0.2	us
	OE-B	P-P	0.3	0.2	0.2	0.2	0.2	us
t_{DIS}	OE-A OE-B	P-P	0.4	0.4	0.4	0.4	0.4	us
t_{RA}	A port rise time	P-P	3 15	3.1 11.9	2 7.3	2.1 6.4	2.2 5.8	ns
		O-D	135 1050	155 996	110 692	93 529	68 411	
t_{RB}	B port rise time	P-P	3 15	2.8 10.5	1.8 6.5	1.3 5.1	0.7 3.4	ns
		O-D	135 1050	132 1001	107 693	79 520	41 353	
t_{FA}	A port fall time	P-P	3 15	2.1 10	1.5 5.7	1.2 4.9	1.3 4.5	ns
		O-D	3 15	2.2 10	1.5 6.6	1.2 5.2	1.1 4.5	
t_{FB}	B port fall time	P-P	3 15	2 10	1.4 6.3	0.9 4.1	0.7 3	ns
		O-D	3 15	0.8 10	0.4 6.5	0.5 5.4	0.4 3	
$t_{SK(O)}$	Chan- el-to-Ch annel	P-P	1	1	1	1.2	1	ns
Max data rate	A to B	P-P	50	80	100	100	100	Mbps
		O-D	2	2	2	2	2	
Max data rate	B to A	P-P	100	100	100	100	100	Mbps
		O-D	2	2	2	2	2	

Note 1: P-P means push-pull; O-D means Open-drain.

Note 2: The duty cycle of the output signal ranges from 40% to 60%.

6.5 Switching Characteristics (Note 1, 2) (continued)

Over recommended operating free-air temperature range, $V_{CCA} = 3.3V \pm 0.3V$ (unless otherwise noted).

Parameter	Test Conditions		V_{CCB} (V)					Unit
			1.5 $\pm$ 0.1	1.8 $\pm$ 0.15	2.5 $\pm$ 0.2	3.3 $\pm$ 0.3	5 $\pm$ 0.5	
			Min Max	Min Max	Min Max	Min Max	Min Max	
t_{PHL}	A-B	P-P	20	13	8	6.8	5.5	ns
		O-D	4 20	3.6 13.5	2.4 10	2 8.5	1.9 7.8	
t_{PLH}	A-B	P-P	15	9	6	4.3	3.9	ns
		O-D	190 820	194 729	149 592	111 439	87 352	
t_{PHL}	B-A	P-P	20	13	9.4	7.5	6.8	ns
		O-D	4 20	3.4 13.5	2.5 10	2.1 8.8	1.7 7.8	
t_{PLH}	B-A	P-P	15	10.2	5.9	5.1	4.3	ns
		O-D	190 850	197 733	150 595	112 449	86 339	
t_{EN}	OE-A	P-P	50	30	30	5	0.2	us
	OE-B	P-P	0.4	0.3	0.2	0.2	0.2	us
t_{DIS}	OE-A OE-B	P-P	0.4	0.4	0.4	0.4	0.4	us
t_{RA}	A port rise time	P-P	3 4	3.1 4	2 4	1.8 4.5	1.9 5	ns
		O-D	135 1050	155 996	110 692	75 580	57 488	
t_{RB}	B port rise time	P-P	3 15	2.8 10.5	1.8 6.5	1.5 5	1 3.6	ns
		O-D	135 1050	132 1001	107 693	72 580	40 485	
t_{FA}	A port fall time	P-P	3 5	2.1 5	1.5 5	1.2 4.5	1.1 3.5	ns
		O-D	3 5	2.2 5	1.5 5	1.1 4.4	1 3.7	
t_{FB}	B port fall time	P-P	3 10	2 10	1.4 5	1.1 4.2	0.8 3.1	ns
		O-D	3 10	0.8 10	0.4 5	1 4.2	0.8 3.1	
$t_{SK(O)}$	Chan- el-to-Ch annel	P-P	1	1	1	1	1	ns
Max data rate	A to B	P-P	50	70	100	100	100	Mbps
		O-D	2	2	2	2	2	
Max data rate	B to A	P-P	100	100	100	100	100	Mbps
		O-D	2	2	2	2	2	

Note 1: P-P means push-pull; O-D means Open-drain.

Note 2: The duty cycle of the output signal ranges from 40% to 60%.

6.5 Switching Characteristics (Note 1, 2) (continued)

Over recommended operating free-air temperature range, $V_{CCA} = 5V \pm 0.5V$ (unless otherwise noted).

Parameter	Test Conditions		V _{CCB} (V)										Unit
			1.5±0.1		1.8±0.15		2.5±0.2		3.3±0.3		5±0.5		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{PHL}	A-B	P-P	20		13		8		6.8		5.5		ns
		O-D	4	20	3.6	13.5	2.4	10	2	8.5	1.9	7.8	
t _{PLH}	A-B	P-P	15		9		6		4.3		3.9		
		O-D	190	820	194	729	149	592	111	439	87	352	
t _{PHL}	B-A	P-P	15		13		9.4		7.5		6.8		ns
		O-D	4	15	3.4	13.5	2.5	10	2.1	8.8	1.7	7.8	
t _{PLH}	B-A	P-P	15		10.2		5.9		5.1		4.3		
		O-D	190	850	197	733	150	595	112	449	86	339	
t _{EN}	OE-A	P-P	130		50		50		30		5		us
	OE-B	P-P	0.4		0.4		0.2		0.2		0.2		us
t _{DIS}	OE-A OE-B	P-P	0.4		0.4		0.4		0.4		0.4		us
t _{RA}	A port rise time	P-P	3	4	3.1	4	1	2	1	2	1	2	ns
		O-D	135	1050	155	996	110	692	75	580	57	488	
t _{RB}	B port rise time	P-P	3	15	2.8	10.5	1.8	6.5	1.5	5	1	3.6	ns
		O-D	135	1050	132	1001	107	693	72	580	40	485	
t _{FA}	A port fall time	P-P	3	5	2.1	5	1.5	3	1.2	3.1	1.1	3.5	ns
		O-D	3	5	2.2	5	1.5	3	1.1	3.1	1	3.7	
t _{FB}	B port fall time	P-P	3	10	2	10	1.4	5	1.1	3.2	0.8	3.1	ns
		O-D	3	10	0.8	10	0.4	5	1	3.2	0.8	3.1	
t _{SK(O)}	Channe l-to-Ch annel	P-P	1		1		1		1		1		ns
Max data rate	A or B	P-P	50		70		100		100		100		Mbps
		O-D	2		2		2		2		2		
Max data rate	B to A	P-P	100		100		100		100		100		Mbps
		O-D	2		2		2		2		2		

Note 1: P-P means push-pull; O-D means Open-drain.

Note 2: The duty cycle of the output signal ranges from 40% to 60%.

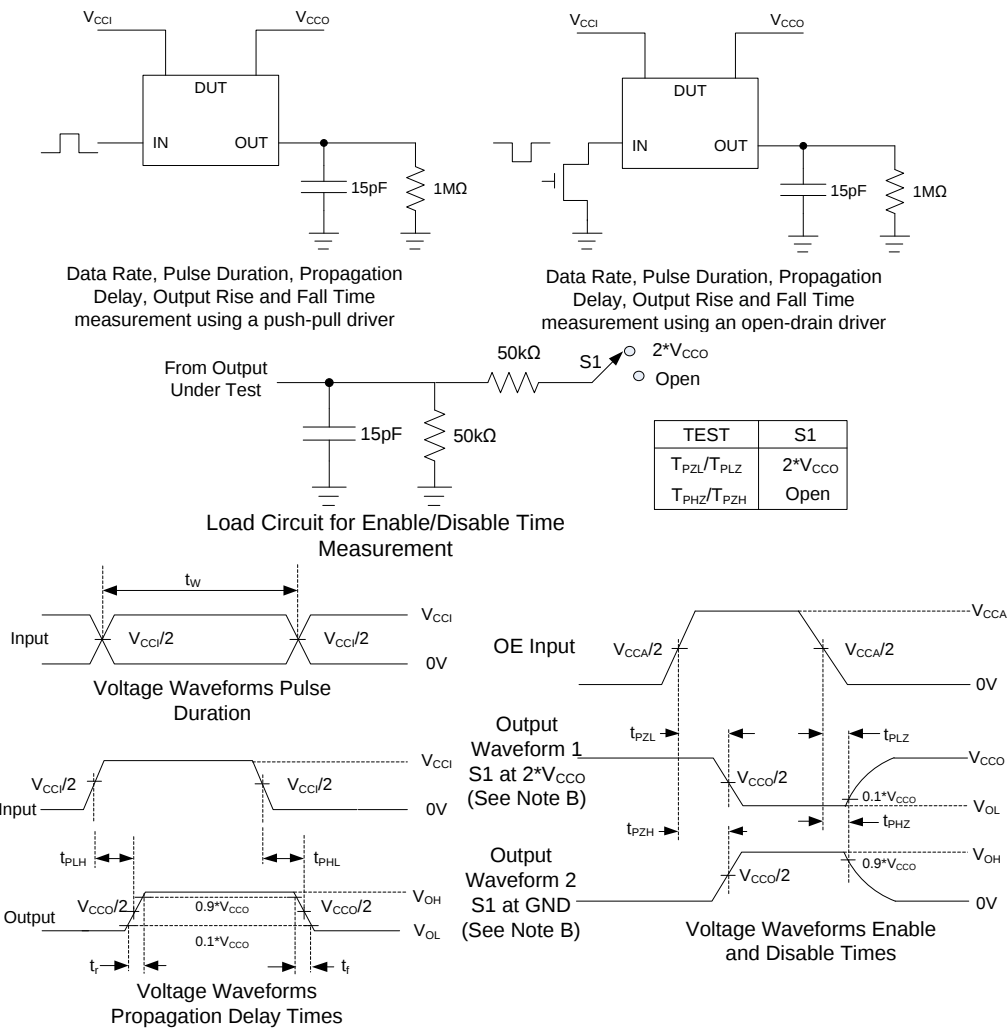
6.6 Operating Characteristics: $V_{CCA} = 1.5\text{ V to }2.5\text{ V}$, $V_{CCB} = 1.5\text{ V to }2.5\text{ V}$ $T_A = 25^\circ\text{C}$.

Parameter	Test Conditions		$V_{CCA}=1.5V$, $V_{CCB}=1.5V$			$V_{CCA}=1.8V$, $V_{CCB}=1.8V$			$V_{CCA}=2.5V$, $V_{CCB}=2.5V$			Unit
			Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
C_{PDA}	$C_L = 0$, $f = 10\text{ MHz}$, $t_R = t_F = 1\text{ ns}$, $OE = V_{CCA}$ (outputs enabled)	A-port input, B-port output	10			12			16			pF
		B-port input, A-port output	11			13			18			
C_{PDB}		A-port input, B-port output	11			13			18			
		B-port input, A-port output	10			12			16			

6.6 Operating Characteristics (continued): $V_{CCA} = 3.3\text{ V to }5.0\text{ V}$, $V_{CCB} = 3.3\text{ V to }5.0\text{ V}$ $T_A = 25^\circ\text{C}$.

Parameter	Test Conditions		$V_{CCA}=3.3V$, $V_{CCB}=3.3V$			$V_{CCA}=5.0V$, $V_{CCB}=5.0V$			Unit
			Min	Typ	Max	Min	Typ	Max	
C_{PDA}	$C_L = 0$, $f = 10\text{ MHz}$, $t_R = t_F = 1\text{ ns}$, $OE = V_{CCA}$ (outputs enabled)	A-port input, B-port output	21			38			pF
		B-port input, A-port output	24			42			
C_{PDB}		A-port input, B-port output	24			42			
		B-port input, A-port output	21			38			

7 Parameter Measurement Information



A. C_L includes probe and jig capacitances.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{MHz}$, $Z_0 = 50\Omega$, $dv/dt \geq 1\text{V/ns}$.

D. The outputs are measured one at a time, with one transition per measurement.

E. T_{PLZ} and T_{PHZ} are the same as t_{DIS} .

F. T_{PZL} and T_{PZH} are the same as t_{EN} .

G. V_{CCI} is the V_{CC} associated with the input port.

H. V_{CCO} is the V_{CC} associated with the output port.

I. All parameters and waveforms are not applicable to all devices.

Figure 7-1. Load Circuits and Voltage Waveforms

8 Detailed Description

8.1 Architecture

The UM3284F is Semi-Buffered Architecture (Figure 8-1). Each channel has edge-rate accelerator circuitry (for both the high-to-low and low-to-high edges), a high-on-resistance N-pass MOSFET (on the order of 300 Ω to 500 Ω) and pull-up resistors (to provide DC-bias and drive capabilities). In a high state, the N-pass MOSFET switch off and the output can maintain high by R_{PU} . While in a low state, the N-pass MOSFET switch on and the output is driven to low by external driver. In both states, the output is designed to weak, so that they can be overdriven by an external driver when data on the bus starts flowing to the opposite direction.

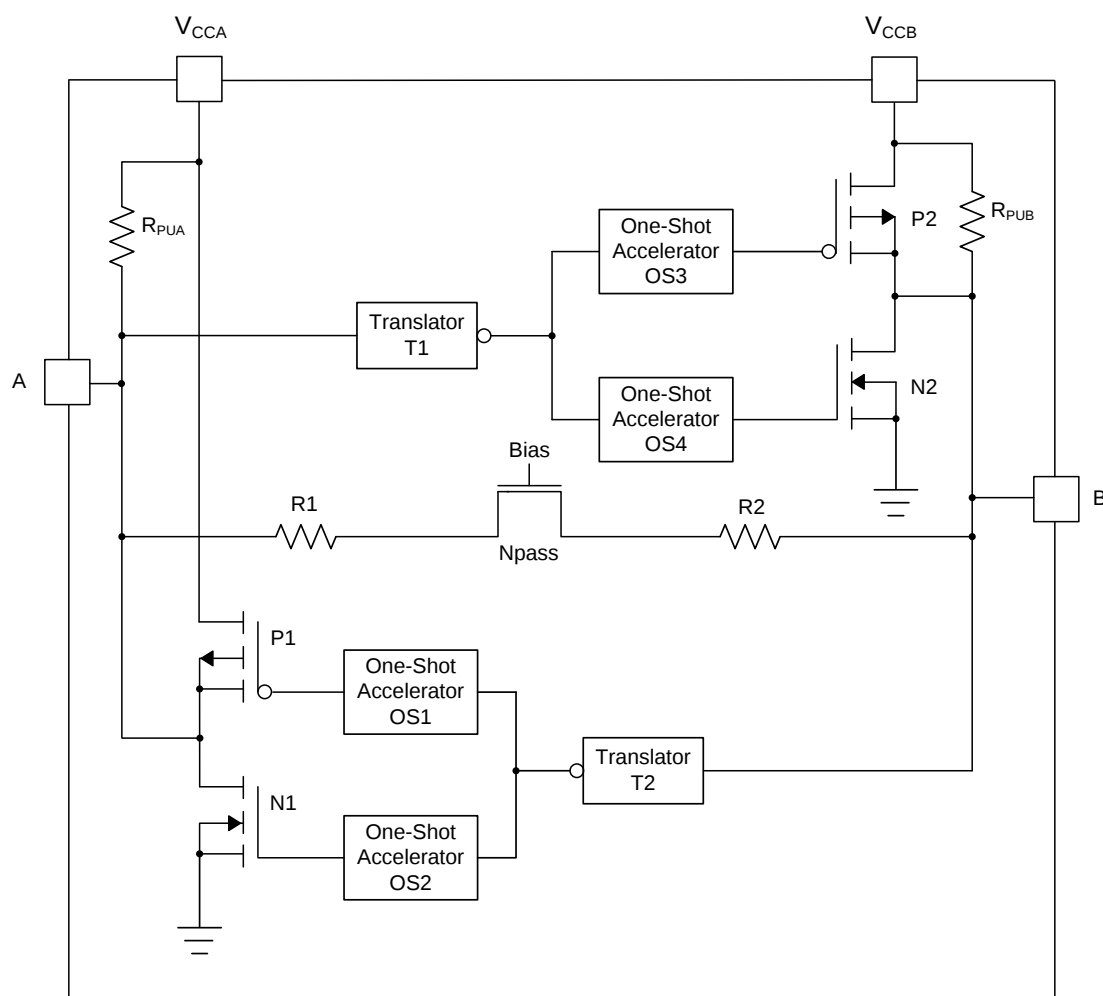


Figure 8-1. Architecture of UM3284F I/O Cell

The output one-shot detects rising or falling edges on the A or B ports. During a rising edge, the one-shot turns on the PMOS transistors (P1, P2) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one-shot turns on the NMOS transistors (N1, N2) for a short duration, which speeds up the high-to-low transition.

8.2 Input Driver Requirements

The fall time (t_{FA} , t_{FB}) of a signal depends on the edge-rate and output impedance of the external device driving UM3284F data I/Os, as well as the capacitive loading on the data lines.

Similarly, the t_{PHL} and maximum data rates also depend on the output impedance of the external driver. The values for t_{FA} , t_{FB} , t_{PHL} , and maximum data rates in the data sheet assume that the output impedance of the external driver is less than 50Ω .

8.3 Output Load Considerations

The PCB layout should be practiced carefully with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper one-shot triggering takes place. PCB signal trace-lengths should be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver.

The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration, also depends on the one-shot output resistance. It is recommended less than 100pF. With very heavy capacitive loads, the one-shot cannot drive fully to the positive rail, retriggering may take place.

8.4 Enable and Disable

The UM3284F has an OE pin input that is used to disable the device by setting the OE pin low, which places all I/Os in the Hi-Z state. The disable time (t_{DIS}) indicates the delay between the time when the OE pin goes low and when the outputs actually get disabled (Hi-Z). The enable time (t_{EN}) indicates the amount of time the design must allow for the one-shot circuitry to become operational after the OE pin goes high.

8.5 Pull-up or Pull-down Resistors on I/O Lines

The UM3284F has the smart pull-up resistors dynamically change value based on whether a low or a high is being passed through the I/O line. Each A-port I/O has a pull-up resistor (R_{PUA}) to V_{CCA} and each B-port I/O has a pull-up resistor (R_{PUB}) to V_{CCB} . R_{PUA} and R_{PUB} have a value of $40k\Omega$ when the output is driving low. R_{PUA} and R_{PUB} have a value of $4k\Omega$ when the output is driving high. R_{PUA} and R_{PUB} are disabled when OE=Low. This feature provides lower static power consumption (when the I/Os are passing a low), and supports lower V_{OL} values for the same size pass-gate transistor, and helps improve simultaneous switching performance

When an open-drain driver is connected to the data I/Os, Each port is at a low level with an internal pull-up resistance of $40k\Omega$, that seriously affecting the t_R of the input signal, and the communication speed. It is recommended adding an external pull-up resistor in the input pin that can decrease t_R and improve communication rate. Normally, an additional $4k\Omega$ pull-up resistor is added to the input side to increase the communication rate by 1Mbps, and so on.

9 Application Information

9.1 Application Information

The UM3284F can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The A-port accepts I/O voltages ranging from 1.1 V to 5.5 V. The B-port accepts I/O voltages from 1.1 V to 5.5 V. The device is ideal for use in application where an open-drain driver is connected to the data I/Os and can also be used in applications where a push-pull driver is connected to the data I/Os. The device has edge rate accelerators (one-shot) to improve the data rate. The pull-up resistors (R_{PU}), commonly used in open-drain applications, have been conveniently integrated so that an external resistor is not needed.

9.2 Typical Application

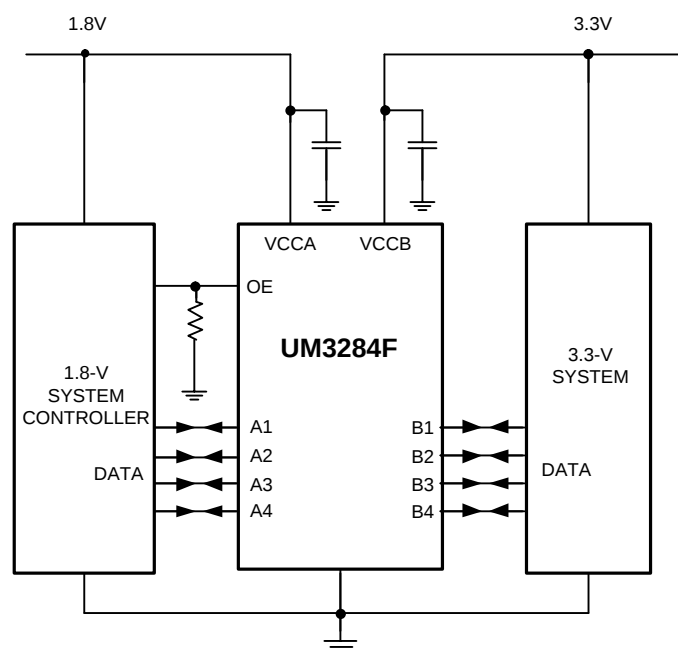
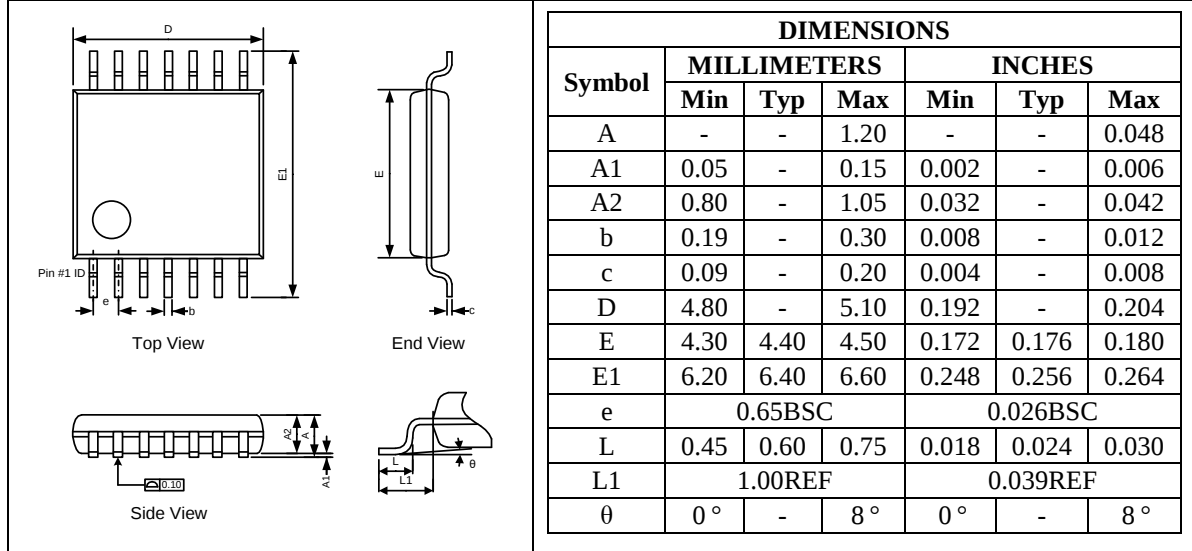


Figure 9-1. UM3284F Typical Application

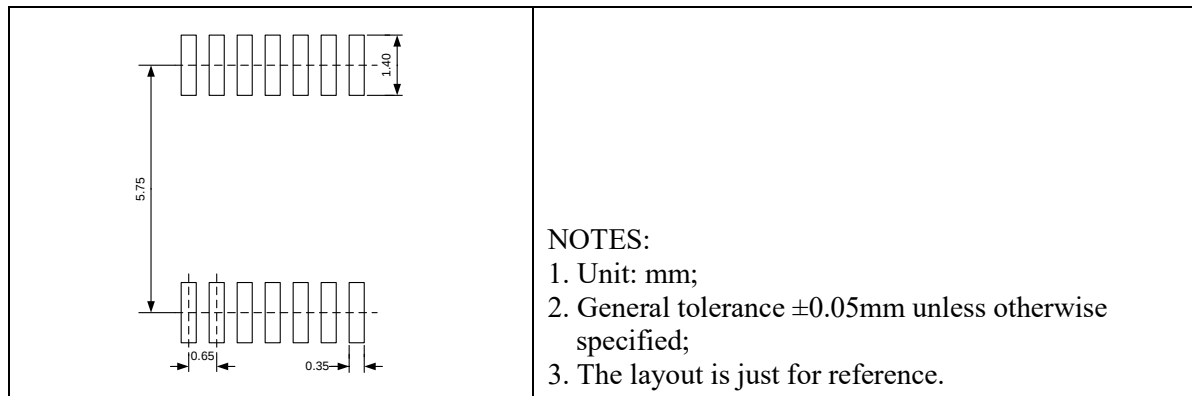
Package Information

TSSOP14

Outline Drawing



Land Pattern

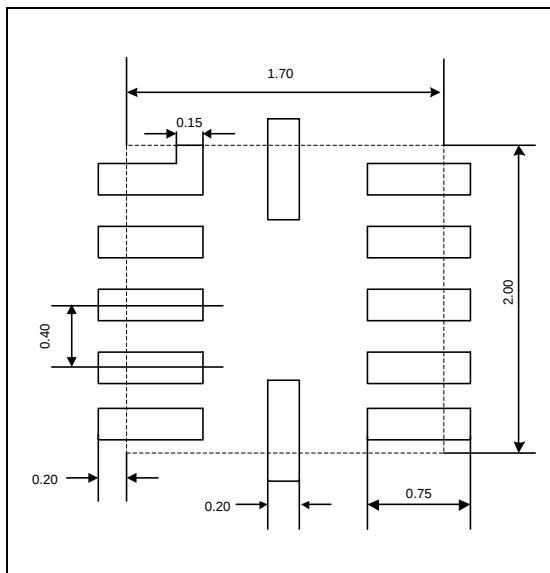


QFN12 1.7×2.0

Outline Drawing

DIMENSIONS						
Symbol	MILLIMETERS			INCHES		
	Min	Typ	Max	Min	Typ	Max
A	0.45	-	0.55	0.018	-	0.022
A1	0.00	-	0.05	0.000	-	0.002
A3	0.152REF			0.006REF		
b	0.15	-	0.25	0.006	-	0.010
D	1.60	1.70	1.80	0.063	0.067	0.071
E	1.90	2.00	2.10	0.075	0.079	0.083
e	0.40TYP			0.016TYP		
k	0.20MIN			0.008MIN		
L	0.40	-	0.60	0.016	-	0.024
L1	0.150REF			0.006REF		

Land Pattern

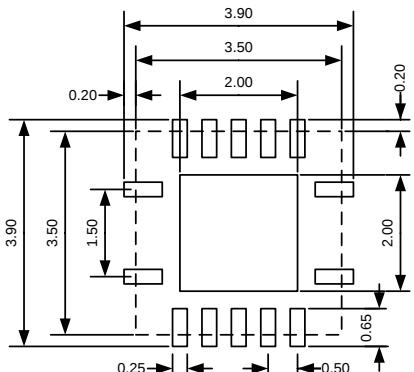
	NOTES: 1. Unit: mm; 2. General tolerance $\pm 0.05\text{mm}$ unless otherwise specified; 3. The layout is just for reference.
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QFN14 3.5×3.5

Outline Drawing

DIMENSIONS						
Symbol	MILLIMETERS			INCHES		
	Min	Typ	Max	Min	Typ	Max
A	0.700	-	0.850	0.028	-	0.031
A1	0.000	0.020	0.050	0.000	0.0008	0.002
A3	0.203REF			0.008REF		
D	3.424	3.500	3.576	0.135	0.138	0.141
E	3.424	3.500	3.576	0.135	0.138	0.141
D1	1.900	-	2.150	0.077	-	0.085
E1	1.900	-	2.150	0.077	-	0.085
k	0.200MIN			0.008MIN		
b	0.200	0.250	0.300	0.008	0.010	0.012
e	0.500TYP			0.020TYP		
e1	1.500TYP			0.059TYP		
L	0.324	-	0.476	0.013	-	0.019

Land Pattern

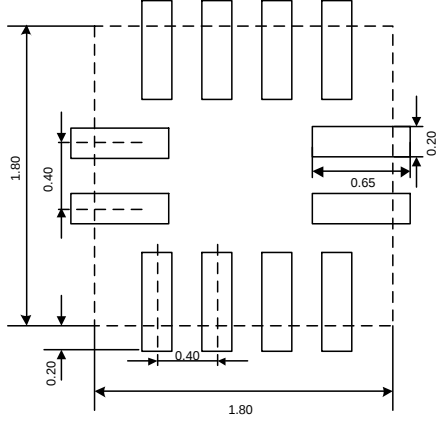
	NOTES: 1. Unit: mm; 2. General tolerance $\pm 0.05\text{mm}$ unless otherwise specified; 3. The layout is just for reference.
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QFN12 1.8×1.8

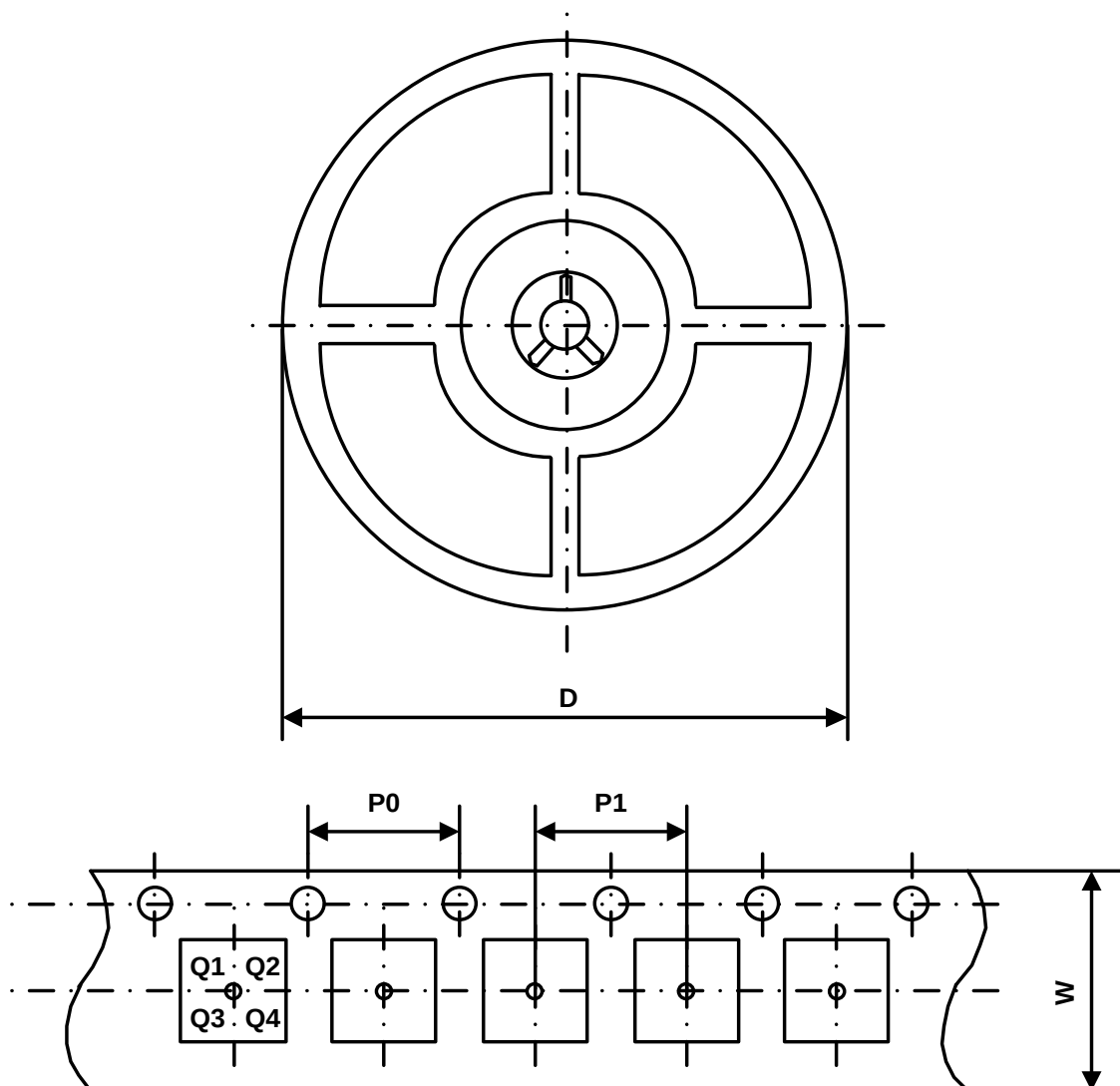
Outline Drawing

DIMENSIONS						
Symbol	MILLIMETERS			INCHES		
	Min	Typ	Max	Min	Typ	Max
A	0.50	0.55	0.60	0.020	0.022	0.024
A1	0.00	0.02	0.05	0.000	0.001	0.002
A3	0.127REF			0.005REF		
b	0.15	0.20	0.25	0.006	0.008	0.010
D	1.75	1.80	1.85	0.069	0.071	0.073
E	1.75	1.80	1.85	0.069	0.071	0.073
e	0.35	0.40	0.45	0.014	0.016	0.018
L	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.375	0.425	0.475	0.015	0.017	0.019

Land Pattern

	NOTES: - Unit: mm. - General tolerance $\pm 0.05\text{mm}$ unless otherwise specified. - The layout is just for reference.
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Packing Information



Part Number	Package Type	Carrier Width (W)	Pitch (P0)	Pitch (P1)	Reel Size (D)	PIN 1 Quadrant
UM3284FUE	TSSOP14	12 mm	4 mm	8 mm	330 mm	Q1
UM3284FQA	QFN12 1.7×2.0	8 mm	4 mm	4 mm	180 mm	Q1
UM3284FQS	QFN14 3.5×3.5	12 mm	4 mm	8 mm	330 mm	Q1
UM3284FQV	QFN12 1.8×1.8	8 mm	4 mm	4 mm	180 mm	Q1

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